NSN 5961-01-414-8640

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View Online at https://aerobasegroup.com/nsn/5961-01-414-8640 **Inclosure Material:** Plastic **Overall Length:** Between 0.110 inches and 0.122 inches **Overall Height:** 0.033 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sot-143 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 drain to gate voltage and 20.0 drain to source voltage and 25.0 gate to source voltage **Current Rating Per Characteristic:** 50.00 milliamperes drain current **Power Rating Per Characteristic:** 350.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 4 printed circuit Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: